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Oxygen, nitrogen co-doped molybdenum disulphide nanoflowers for an excellent antifungal activity†

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The engineering of pristine low dimensional materials towards society-needed functionalities is the driving force for cultivation the field of nano-bio research. Herein, the molybdenum disulphide structure has been ornamented with nitrogen as well as oxygen atoms by a facile chemical route. This O,N co-doped MoS₂ nanoflower sample along with only-N-doped MoS₂ samples were investigated structurally and chemically to ascertain the successful attachment of the dopant atoms and its associated changes in the structure. While positron annihilation spectroscopy demonstrates detailed defect pictures of these two variants with not much of a difference, the electron paramagnetic resonance displays the adequacy of Mo⁵⁺ defect states in O,N co-doped MoS₂ compared to the only-N-doped MoS₂ sample. Moreover, this O,N co-doped MoS₂ exhibits outstanding antifungal activities towards two harmful fungal pathogens, namely, *Alternaria alternata* and *Fusarium oxysporum*, in dark as well as in light. MoS₂, which otherwise showed no antifungal growth inhibition whatsoever, can thus be promoted to get exalted antifungal performance by gradual incorporation of nitrogen and oxygen atoms within the lattice of MoS₂. This study establishes a new pathway to design better candidates for antifungal activity with lesser chances of antimicrobial resistance through suitable elemental engineering and is a prime need for our society to cope with the growing unforeseen dangers.

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1. Introduction

In the wake of the vast catastrophe foisted on by the potato late blight-led Irish famine that went on to change the course of European history,¹ it became truly imperative to develop rigorous pre-emptive measures to combat such invasive fungal infections in times to come. However, over the past centuries, the numerals of fungi or fungus-like oomycetes causing virulent diseases have only proliferated to pose a grave threat to the ecosystem. If not checked in time, this would not only put the ecological homeostasis at stake but also potentially

disrupt the food security, consequentially leading to a debilitated agricultural output. Furthermore, the efficacy of the presently available antifungal remedies in humans, namely, polyenes, azoles, flucytosine, and echinocandins has plateaued out² and the incidences of invasive fungal infections in immuno-compromised human population are incessantly on the rise.³ Ironically, the presence of several limitations, such as off-target toxicity, adverse interactions with other drugs, and the emergence of antifungal resistant strains have rendered these existent antifungals delimited in combating refractory and invasive fungal infections. The use of chemical-based pesticides, on the other hand, in the management of pre- and post-harvest decay and diseases in crops has been a long-standing issue of concern in the light of environmental pollution and safety in consuming foods ensuing out of toxic residuals of these fungicides.⁴ Therefore, it is essential to develop new environment-friendly antifungal nanomaterials with lower levels of toxicity and less chances of microbial resistance. In this matter, nanomaterial-based antifungals have evolved to be an exceptional alternative.⁵ The repertoire of nanomaterials explored so far in combating microbial invasions comprises of plasmonic nanoparticles,⁶ metal oxides,^{7,8} graphene oxide,⁹ graphene-based derivatives,^{10,11} and various

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hetero-structured nanocomposites.^{12–15} Of late, inspired by the grand success of graphene and graphene-based nanomaterials in antimicrobial activity, layered 2D materials, particularly molybdenum disulphide (MoS₂), have started to garner lot of interest in this field. However, till now, reports on the antifungal activities of MoS₂ are strikingly very few in number.

Owing to the innumerable novel and intriguing properties arising due to quantum confinement in the third dimension, MoS₂, a layered transition metal dichalcogenide, has found extensive applications in transistors,¹⁶ optoelectronic devices,¹⁷ spintronics,¹⁸ sensors,¹⁹ catalysts,²⁰ photodetectors,²¹ energy storage devices,²² biomedicine,²³ etc. In MoS₂, a layer of Mo atoms is sandwiched between two layers of S atoms held by strong covalent bonding.²⁴ However, due to the weak interlayer van der Waals force, mono- or few-layered MoS₂ nanosheets with large specific surface area can be easily extracted from the bulk analogues by mechanical or chemical exfoliation methods.²⁴ In addition, fluorescence or quenching of the fluorescence properties, which are entirely dependent on the thickness of the layers and the crystal structure,^{25,26} strong near-infrared region absorbance, and high photothermal quenching efficiency,²⁷ have enabled the use of MoS₂ in various biomedical applications including bio-sensing, bio-imaging, cancer therapy, drug delivery, antibacterial wound healing, and tissue regeneration.^{28,29} In spite of all these bio-related applications, the antifungal activities of 2D MoS₂ have remained largely unexplored till now. Although pristine bulk MoS₂ has been hardly reported to exhibit any microbial inhibition, by controlling the thickness of the layers, lateral size, and crystal structure, the desired antimicrobial properties may be enforced within MoS₂. Liu *et al.* demonstrated the photocatalytic bacterial disinfection of water by few-layered vertically aligned MoS₂ nanofilms.³⁰ Recently, Xu *et al.* showed that nanoflowers of MoS₂ exhibited better antibacterial capabilities than the MoS₂ nanosheets.³¹ Surface functionalization with hydrophobic ligands,³² antimicrobial peptides,³³ and loaded antibiotics³⁴ have been found to induce antimicrobial properties within the MoS₂ nanosheets as well. Another fruitful strategy to impose antimicrobial behavior within the MoS₂ nanosheets is to combine them with other antimicrobial nanomaterials such as silver and graphene oxide.³⁵ Zhang *et al.* showed that chitosan and silver nanoparticle-modified MoS₂ exhibited effectively large antifungal inhibition of *Saccharomyces uvarum* and *Aspergillus niger*.³⁶ However, in all these cases, the bactericidal activities were observed to be engendered by light-dependent stimulations, which would therefore wholly restrain the scope of application of these antimicrobials for disinfection in implantable medical devices. In our previous work,³⁷ we have shown that the defect sites, which are relatively abundant in MoS₂, can be advantageously manipulated through nitrogen doping to make them suitable for the generation of reactive oxygen species (ROS) in dark as well, thereby invoking antifungal properties within it. Therefore, it was found that the advantageous design of the material in an appropriate way holds the key to attain success in developing powerful antifungals from MoS₂ nanostructures; this is a relatively new and interesting field of study that requires intensive research work.

Here, in this work, we designed MoS₂ nanostructures through suitable elemental doping and demonstrate how doping helps in significantly inducing high antifungal abilities in the MoS₂ nanostructures, which would otherwise have no inhibitory effect on the fungal growth of phytopathogens. Moreover, we shall explain how the efficacy of the induced antifungal activity evolves on being co-doped with elements of differing electronegativities. Doping has always been a useful strategy to tune and reform functionalities such as electronic, magnetic, and catalytic.^{38–40} Interestingly, oxygen incorporation has been previously reported to have enhanced the catalytic performances in electrocatalytic hydrogen generation,^{39,40} supercapacitor,⁴¹ etc., but there are no reports on the doping by oxygen to achieve antifungal performances in MoS₂ so far. Herein, we successfully doped oxygen in MoS₂ in addition to N-doping through the facile hydrothermal method and studied its antifungal activities on *Alternaria alternata* and *Fusarium oxysporum* as version representatives of harmful fungal pathogens. Both these species have devastating effects not just on agricultural plants, leading to huge losses during the pre and post-harvest phases but also immunity-compromised humans and animals as well. Hence, the need to develop effectively potent antifungals to combat these fungal pathogens has grown to be an absolute necessity. Further, to get a comprehensive insight into the origin of the antifungal activities in these doped samples, various characterisation techniques were adopted and a possible mechanism and pathway leading to the fungal deaths has also been proposed.

2. Experimental section

2.1 Materials

All the chemicals and reagents were of analytical grade and purchased from Sigma Aldrich. They were used without any further purification.

2.2 Synthesis of nitrogen-doped MoS₂ and oxygen–nitrogen co-doped MoS₂

Here, in this work, nitrogen-doped molybdenum disulphide and oxygen–nitrogen co-doped MoS₂ nanostructures, henceforth referred to as NMS and ONMS, respectively, were successfully synthesized through an optimised one-step hydrothermal method. On the other hand, bulk MoS₂, henceforth referred to as MS in the text, of analytical grade was procured commercially from Sigma Aldrich. In order to prepare nitrogen-doped MoS₂ (NMS), 0.5038 g of molybdenum trioxide (MoO₃) dissolved in 15 mL of DI water was added drop-wise to 0.8 M aqueous solution of thiourea (CSN₂H₄) and stirred vigorously on a magnetic stirrer for an hour. The resultant bluish white solution was then transferred to an autoclave of capacity 75 mL and heated in an oven at 180 °C for 48 hours. The black product so obtained was washed several times with de-ionised water and eventually dried at 60 °C to obtain the nitrogen-doped MoS₂ powder (NMS). Further, oxygen–nitrogen co-doped MoS₂ (ONMS) was prepared via a similar hydrothermal procedure, wherein the same precursor



ratio and reaction temperature were maintained but the time of hydrothermal reaction was reduced to 18 hours.

2.3 Characterisation

In order to obtain the X-ray diffraction patterns, the synthesized powder samples were scanned in the 2θ range of 3° – 80° with a step size of 0.02° in a Rigaku Miniflex X-ray diffractometer having CuK α radiation source of wavelength 1.5418 Å. A scanning electron microscope from Zeiss was used to analyse the morphology of the as-synthesized samples. Further, the transmission electron microscopy analysis of the obtained samples was done on a FEI-made Technai G2 20 Twin high resolution transmission electron microscope. The surface area measurements (BET) and pore size analysis was performed on the AutosorbIQ station from Quantachrome instruments. The Renishaw inVia Raman microscope was utilised to acquire the Raman spectra with an excitation wavelength of 532 nm at the room temperature. The X-ray photoelectron spectroscopy studies were recorded using a ULVAC-PHI5000 Versa Probe II spectrometer equipped with an Al K α radiation source having 1486.6 eV of photon energy. The X-band electron paramagnetic resonance signals were recorded on the Bruker-made ELEXSYS E580 pulsed electron paramagnetic resonance spectrometer at room temperature. The microwave power for the measurements were fixed at 15 mW. The details of positron annihilation spectroscopy (PAS) and coincidence Doppler broadening spectroscopy (CDBS) experiments are provided in the ESI[†] (Section S1.1).

2.4 Antifungal studies

2.4.1 Materials. *Alternaria alternata* (NFCCI-3151) and *Fusariumoxysporum* (NFCCI-2360), used as the model fungal pathogens, were purchased from Agharkar Research Institute, Pune, India.

2.4.2 Maintenance of the fungal culture. The fungal pathogens were maintained in Potato Dextrose Agar (PDA) slants and grown at 30 °C temperature for 7 days. The fungal cultures were preserved at 4 °C and grown freshly before every experiment.

2.4.3 Fungitoxicity assay. The details of the fungitoxicity assay include the growth inhibition test, Triphenyl Tetrazolium Chloride (TTC) assay, scanning electron microscopy analysis, and fluorescence microscopy studies to detect fungal cell death and ROS generation is given in the ESI[†] (Sections S1.2.1–S1.2.4).

3. Results and discussion

Here, in this work, the incorporation of only nitrogen atoms in the case of NMS and both oxygen and nitrogen in the case of ONMS as dopants within the lattice was optimised and achieved through sustainable control on the time over which the reaction took place. NH₃ evolution as a by-product in the thermal decomposition of thiourea accounts for the nitrogen atoms being doped within the MoS₂ lattice, which according to our previous study, are most likely to occupy the S-sites in the Mo-rich limit.³⁷ However, in order to ensure the incorporation of oxygen into the MoS₂ lattice in addition to the nitrogen

atoms, the reaction time had to be substantially brought down to 18 hours. The reduced reaction time effectively rendered the reaction process insufficient for the complete conversion of MoO₃ to MoS₂. Hence, traces of unsaturated Mo–O bonds, inherited from the MoO₃ precursor, remained within the lattice of MoS₂ to ensure the presence of oxygen atoms within the MoS₂ lattice. Previously, in a similar kind of synthetic procedure, Xie *et al.* had incorporated oxygen in MoS₂ nanosheets by controlling the crystallisation process through temperature variation in order to achieve enhanced electro-catalytic activity in the hydrogen evolution reaction.⁴⁰ Besides, in earlier works, surface oxidation achieved through various other methods such as exposure to high energy RF oxygen plasma,⁴² remote plasma,⁴³ 1.5–5 eV atomic oxygen flux,⁴⁴ UV-ozone exposure,⁴⁵ and annealing in a high temperature oxygen environment,⁴⁶ were used. These are rather harsh methods and resulted in non-uniform lateral oxidation and in-depth lattice etching. In contrast, the strategy adopted in this present work is a far more simplistic approach, resulting in a high percentage of oxygen doping.

In order to determine the morphology and microstructure of the as-grown doped MoS₂ samples, scanning electron microscopy (SEM) and transmission electron microscopy (TEM) were conducted. The SEM images, as shown in Fig. 1(a) and (b), reveal almost similar kinds of flower-like morphology for both NMS and ONMS. However, in the case of ONMS, the MoS₂ nanosheets, which assembled themselves into a flower-like motif, are apparently seen to be considerably thickened and also have surface roughness. Further, in ONMS, the edges of the nanosheets are obscure, suggesting insufficient crystallisation due to reduced reaction time. On the contrary, the NMS sheets have relatively sharper edges and reveal better crystallinity. The high magnification TEM images [Fig. 1(c) and (d)] further indicate the assemblage of nanosheets in a flower-like manner, as obtained from scanning electron microscopy. The high-resolution transmission electron microscopy (HRTEM) images reveal an enlarged *d*-spacing of ~0.855 nm ONMS compared to that of 0.66 nm [Fig. 1(e) and (f)]. In congruence with the earlier studies,^{39–41} this enlargement in the interplanar *d*-spacing can be attributed to the incorporation of oxygen in the MoS₂ lattice. However, the *d*₀₀₂ value calculated from the fringes of NMS agrees well with the reported values of 2H-MoS₂.³⁷ In addition to this, X-ray diffraction (XRD) studies were carried out on the synthesized samples in order to figure out the crystal structure. The XRD pattern for NMS, as shown in Fig. 2(a), matches well with the data of 2H-MoS₂ (JCPDS card no. 87-2416). The interplanar spacing (*d*₀₀₂) calculated from the XRD peak value agrees well with those calculated from the HRTEM fringes. However, as evident from Fig. 2(a), two new peaks at 10.28° and 16.87° were seen to emerge for ONMS. The *d*-spacing calculated for these two peaks is 0.861 nm and 0.524 nm, respectively. This diploidic relation corresponding to the interplanar spacing unambiguously suggests that a new lamellar structure with an expanded interplanar spacing has been formed. This possibly accounts for the thickening of the nanosheets in ONMS as observed from the SEM images. The simulated XRD pattern for oxygen incorporated MoS₂ nanosheets



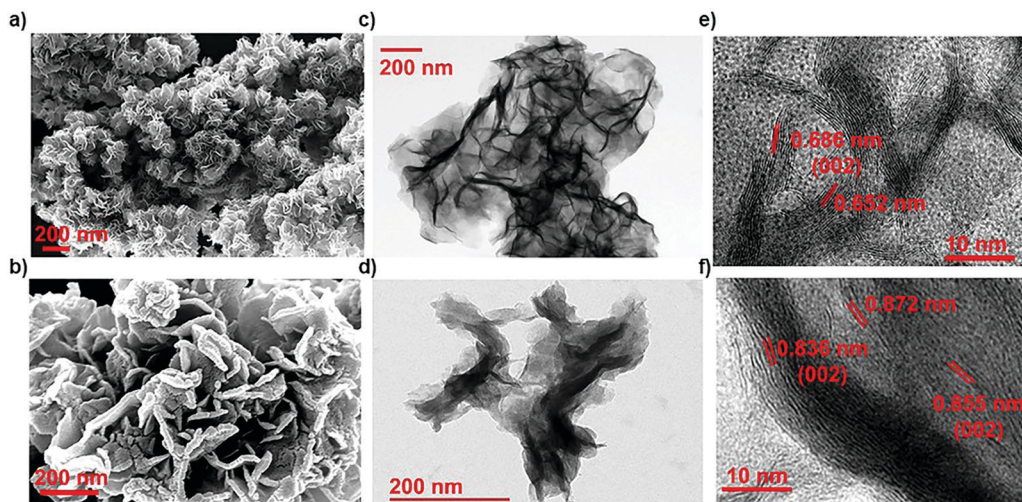


Fig. 1 (a and b) Scanning electron microscopy images of (a) NMS, and (b) ONMS. (c and d) Transmission electron microscopy images of (c) NMS and (d) ONMS. (e and f) HRTEM images of (e) NMS and (f) ONMS, showing enlarged interplanar spacing.

taken from Xie *et al.* is inserted in Fig. 2(a) for comparison and is seen to match with the XRD peaks of ONMS in the low angle region.⁴⁰ Nonetheless, the XRD peaks in ONMS corresponding to the (102) and (110) planes match with those of 2H-MoS₂.³⁷ The surface area and porosity of the synthesized samples were ascertained by the adsorption–desorption studies of nitrogen. The isotherm plots for ONMS and NMS are shown in Fig. S1 (ESI[†]) and suggest the presence of mesopores within the samples. Applying Brunauer–Emmett–Teller (BET) analysis, the surface areas for ONMS and NMS were calculated to be 6.507 m² g^{−1} and 6.484 m² g^{−1}, respectively. Further, the average pore radius in ONMS was 38.468 Å with a total pore volume of 1.252 × 10^{−2} cc g^{−1} for the pores of radius less than 144.9 nm (*P/P*₀ = 0.993). In contrast, NMS showed a marginally increased average pore radius of 40.78 Å with a total pore volume of 1.332 × 10^{−2} cc g^{−1} for the pores of radius less than 210.4 nm (*P/P*₀ = 0.995).

Raman spectroscopy was further employed to look into the modes of vibration in the samples in greater details. In Fig. 2(b), the obtained Raman spectra for NMS and ONMS are shown. In the 2H representative of bulk MoS₂, the two Raman active modes are the E_{2g}¹ mode resulting from the oppositely directed in-plane vibration of the Mo and S atoms and the A_{1g} mode as a consequent of their out-of-plane opposite vibrations.⁴⁷ The E_{2g}¹ and A_{1g} modes occur nearly at 382 cm^{−1} and 407 cm^{−1} in the bulk form of MoS₂.⁴⁷ However, in the case of both ONMS and NMS, the E_{2g}¹ mode is red-shifted by ~4.5 cm^{−1} in comparison to the reported values of 6-layered MoS₂.⁴⁷ This red shift possibly ensues from the lattice distortion invoked by oxygen and nitrogen doping in the samples. This is further reaffirmed by the disorder-prompted symmetry breaking of the E_{2g}¹ mode, causing it to split into the E_{2g}¹⁺ and E_{2g}^{1−} components,^{37,48} as shown in Fig. S2 (ESI[†]). Meanwhile, the A_{1g} Raman mode is red-shifted in ONMS by almost 3 cm^{−1} relative to the 6-layered MoS₂, which is more pronounced than the ~1 cm^{−1} red-shift in the case of NMS. Moreover, the emergence of Raman peaks at 284.32 cm^{−1}, 331.18 cm^{−1}, and 218.75 cm^{−1}, assigned to

the B_{2g}, B_{1g}, and A_g modes of vibration for the Mo–O bonds, reconfirms the successful doping of oxygen in ONMS.^{40,49}

In order to get further insight about the chemical constitution of the as-synthesized samples, X-ray photoelectron spectroscopy (XPS) was performed on the doped MoS₂ samples. The multi-component core level XPS spectra was deconvoluted with the help of mixed Gaussian–Lorentzian product function alongside a Shirley background correction using the CASAXPS software. In NMS, the deconvolution of the core Mo 3d region resulted in two doublets, one between ~228.6 eV and 231.74 eV, and the other between ~228.9 eV and 232.04 eV, as seen from Fig. 3(a). The lower binding energy doublet corresponds to the Mo 3d_{5/2}, and Mo 3d_{3/2} core levels in MoS₂, *i.e.*, Mo⁴⁺ and S^{2−} charge states arising out of S–Mo charge transfer.^{48,50} The corresponding peaks in the core level S 2p spectra for the S^{2−} charge state are seen at 161.61 eV and 162.74 eV. The other doublet in the Mo 3d region, at binding energies higher than the Mo–S peak by ~0.3 eV, which may be attributed to the formation of Mo–N bonds in agreement with the previous reports.⁴⁸ This is further affirmed by the presence of the peak at 397.59 eV in the N 1s region [Fig. 3(c)], which essentially signifies Mo–N bond formation.^{37,48,51} Also, the N 1s region is partially overlapped by the core level Mo 3p_{3/2} region and the peak at 394.47 eV originates from the Mo–S bonds in MoS₂.^{37,48} The remaining peak at ~401 eV arises because of the strongly chemisorbed ammonia.^{37,51} A small hump near 232.95 eV in the Mo 3d region of NMS may be ascribed to superficial oxidation of the synthesized NMS sample instead of any Mo–O bond formation. A similar peak at ~233.4 eV is present in the Mo 3d region of ONMS as well. The absence of any Mo–O peaks in the O 1s region of NMS further substantiates our claim of surface oxidation. The peaks at 531.26 eV, 532.3 eV, and 533.77 eV in the O 1s region of NMS, as shown in Fig. S3(b) (ESI[†]), are primarily due to oxygen in the –OH radical (possibly physisorbed H₂O), O₂ adsorbed from the atmosphere, and physisorbed/chemisorbed H₂O at the surface respectively.^{52–54} Further, the peaks at 226.17 eV and 224.87 eV in



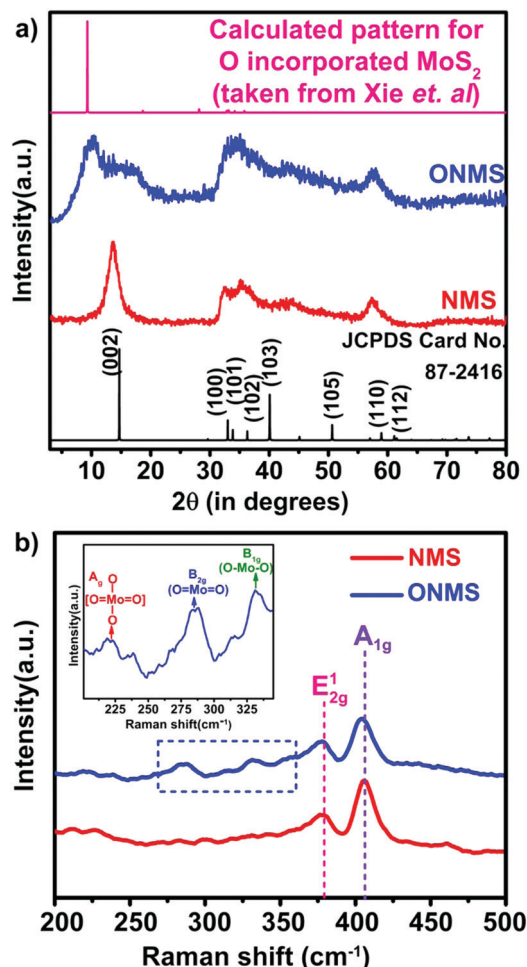


Fig. 2 (a) X-ray diffraction patterns NMS and ONMS. The standard pattern for commercially procured 2H-MoS₂ and the calculated pattern for oxygen-incorporated MoS₂ lattice (taken from Xie *et al.*)⁴⁰ is given as the reference. (b) Raman spectra for NMS and ONMS. The dotted blue rectangle emphasizes the development of the Mo–O bond in ONMS. The inset shows the presence of three Raman peaks assigned to different Mo–O bond formations in ONMS under zoomed condition.

the overlapped S 2s region arise because of Mo–S bonding in MoS₂ and the cluster complexes of Mo and S, respectively.⁵⁵ On the

other hand, in ONMS, the doublets in the Mo 3d region arising out of Mo–S and Mo–N bond formation are shifted down to lower binding energies, as is revealed from Fig. 3(a). The S 2p peaks associated with the S^{2−} state are also downshifted to lower energy values, as shown in Fig. 3(b). The intensity of the doublet arising out of Mo–N bonding, however, decreased for ONMS, suggesting reduced N-doping compared to NMS. In addition to this, another doublet is seen to arise between 229.72 eV and 232.73 eV in Mo 3d region for ONMS. According to earlier reports,⁵⁶ this doublet emerges because of the incorporation of oxygen in MoS₂ to form a MoS_{2−x}O_x-like phase with the Mo⁵⁺ charge state. Further, the peak at 399.162 eV in the overlapped N 1s region of ONMS [Fig. 3(c)], in addition to the little Mo–N peak at 397.44 eV, emerges due to the introduction of Mo–O bonds.⁵⁷ Also, the peak at 530.2 eV in the core level of the O 1s region for ONMS reaffirms the presence of Mo–O bonds⁴¹ in it, as evident from Fig. S3(a) (ESI[†]). However, the other peaks at 531.10 eV and 532.06 eV in the O 1s region are due to the –OH radical and adsorbed oxygen. Hence, it can be inferred that in addition to being nitrogen-doped, oxygen has also been successfully incorporated into the MoS₂ lattice of ONMS through substitutional doping rather than surface oxidation. The downshift of the doublets in the core level Mo 3d region of ONMS, as mentioned before, may be explained to occur as a result of the Fermi level realignment between MoS₂ and MoO_x, giving rise to upward band bending.^{43,58} The peak at 235.29 eV in the Mo 3d region suggests the presence of residual unreacted MoO₃ for ONMS.³⁷ The S 2p region for ONMS [Fig. 3(b)] on being deconvoluted resulted primarily into two doublets, out of which, one with its peaks at 161.17 eV and 162.41 eV arises because of the S^{2−} state of MoS₂ and the other between 162.86 eV and 164 eV results because of the S₂^{2−} state, which is normally seen to accompany the Mo⁵⁺ charge state.^{50,59} The quantitative analysis of the survey spectra, as shown in Fig. S4 (ESI[†]), reveals 15.97% of oxygen doping as well as 4.89% of N-doping in ONMS whereas there is 6.38% nitrogen-doping in NMS.

The X-band electron paramagnetic resonance (EPR) study conducted on the doped MoS₂ samples revealed the presence of a weak broad signal at $\sim g = 2.00$ in both the ONMS and NMS samples, as shown in Fig. 4(a). This signal in the EPR spectrum,

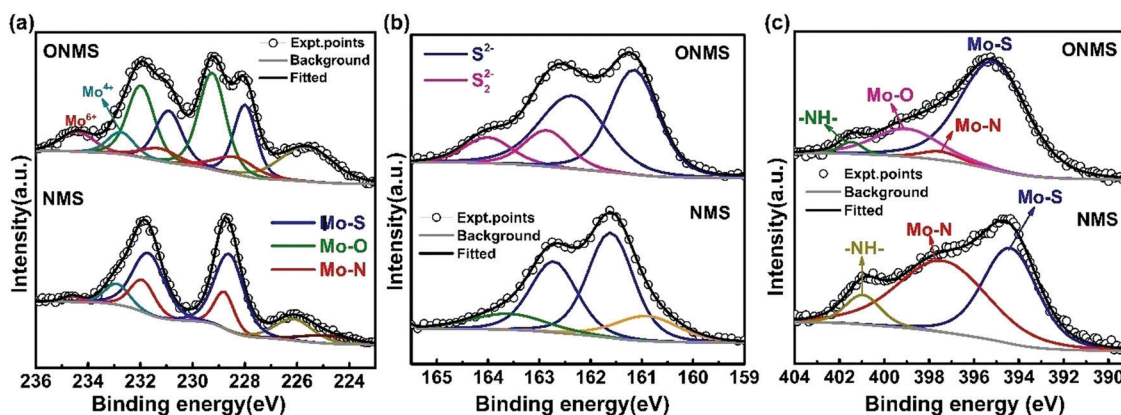


Fig. 3 High resolution X-ray photoelectron spectrum from the (a) Mo 3d, (b) S 2p, and (c) N 1s regions of ONMS and NMS.



according to previous studies, arises due to sulphur-coordinated (thio-Mo⁵⁺) defects in MoS₂.⁶⁰ The intensities of the $\sim g = 2.00$ signal in both ONMS and NMS appear to be almost equal at a glance, indicating that there is not much of a difference in the coordination environment of the sulphur-moderated defect sites or their relative abundance. However, the presence of a peak at $g = 1.9364$ [Fig. 4(a)] for ONMS makes it different from NMS as far as the oxygen-coordinated (oxo-Mo⁵⁺) defect states are concerned. According to earlier reports, the $g = 1.9364$ line arises because of the hyperfine interaction of the unpaired electrons in the Mo⁵⁺ state, which consists of a molybdenyl centre, *i.e.*, a short Mo=O bond surrounded by oxygen ligands in distorted octahedral or square-pyramidal symmetry.^{50,61} Therefore, this strongly evinces the successful doping of oxygen atoms throughout the sample in the case of ONMS.

In order to get a comprehensive insight into the nature of the defect states, as revealed by the EPR spectra, positron annihilation spectroscopy (PALS) was carried out on both ONMS and NMS. The peak-normalised positron lifetime spectra of ONMS and NMS are given in Fig. 4(b). Not much of a difference is observed between the two samples, although the resolved positron lifetimes and intensities (shown in Table 1) are more informative and sharper in detail as far as the sizes and concentrations of the defect structures present in the samples are concerned.

The observation of a third positron(ium) lifetime component τ_3 is quite unnatural for materials with relatively higher electron densities like as MoS₂ since it normally arises due to the formation of positronium (Ps), which is the metastable bound state of an electron and a positron. It can happen in nanocrystalline materials where large intercrystalline boundaries exist, which are characterised by the significantly reduced electron density compared to that of the bulk. However, in this case, the efforts to analyse the spectra with two lifetime components yielded poor reduced χ^2 fit. The three-component analysis also gave scattered values of the third component of lifetime τ_3 and relative intensity I_3 . So, the analyses were done by fixing τ_3 to 0.55 ns, which incidentally is the highest possible positron lifetime when it is annihilated from the nanocrystalline surfaces. From the results shown in Table 1, the first conclusion that can be drawn is the existence of two types of structural defects,

one arising out of the atomistic defects or crystalline vacancies and the other as porous type defects in the free spaces within the molecular assemblage, as revealed by the BET surface analysis. The positron lifetimes τ_2 and τ_3 represent these defects and the magnitudes of these lifetimes also indicate the nature and sizes of the defects. For example, the lifetime of the positrons annihilating from the free state (*i.e.*, not trapped in any defect and diffusing freely through the inter-atomic region) is calculated for both the cases from the relation

$$\frac{1}{\tau_1} = \frac{1}{\tau_b} + \kappa \quad (1)$$

where the positron trapping rate

$$\kappa = \frac{I_2}{I_1} \left(\frac{1}{\tau_b} - \frac{1}{\tau_2} \right) \quad (2)$$

and the value of τ_b so obtained helps to identify the atomistic defects present in the samples. The difference $\tau_2 - \tau_b$, which is 0.1112 ns for the ONMS sample and 0.1147 ns for the NMS sample, corresponds to the defects of divacancy type ($\tau_2 - \tau_b = 0.103$ ns) and trivacancy type ($\tau_2 - \tau_b = 0.1190$ ns) clusters, more or less in equal proportions in ONMS and tending more towards the latter in NMS (Table 1). The intensity I_2 differs by about 4% in the NMS sample, indirectly hinting at a slightly larger defect concentration in it. The defect concentration is calculated from the relation $\kappa = \mu C$ where the specific positron trapping rate μ is 0.590 ns⁻¹ for divacancies and 0.770 ns⁻¹ for trivacancies. For tetravacancy clusters, μ is 0.970 ns⁻¹ and so on.⁶² The estimated defect concentrations are also given in Table 1. The slightly lower value in the ONMS sample is perhaps an indication of the occupancy of some of these defects by oxygen atoms, although the process was not successful enough to reduce their number significantly.

The coincidence Doppler broadening spectra (CDBS), as shown in Fig. 4(c), also give results that are consistent with those obtained from the positron annihilation lifetime measurements. The peak at $P_L = 9.1 \times 10^{-3} m_0 c$ that arises from positron annihilation with the 4p electrons of Mo is stronger in the case of NMS when compared to that of ONMS. This again proves that the defect concentration in NMS is slightly on the higher side. The calculated defect concentration, as obtained

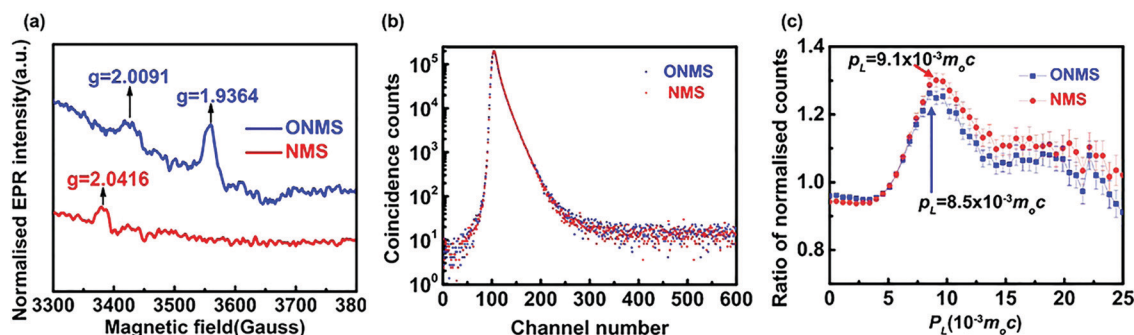


Fig. 4 (a) EPR spectra for ONMS and NMS. (b) Peak normalised positron lifetime spectra for ONMS and NMS. (c) Ratio curves generated from the coincidence Doppler broadening spectra of ONMS and NMS.



Table 1 Summary of the parameters obtained from positron annihilation lifetime spectroscopy for ONMS and NMS

Sample	τ_1 (ns)	τ_2 (ns)	τ_3 (ns)	I_1 (%)	I_2 (%)	I_3 (%)	τ_m (ns)	τ_b (ns)	$\tau_2 - \tau_b$ (ns)	κ (ns ⁻¹)	μ (ns ⁻¹)	C (ppm)
ONMS	0.1014 ± 0.0021	0.2960 ± 0.0034	0.55	34.49 ± 0.82	52.41 ± 0.63	13.10 ± 0.37	0.2621	0.1848	0.1112	3.0891	0.6	5.148
NMS	0.1033 ± 0.0020	0.3047 ± 0.0029	0.55	33.28 ± 0.72	56.52 ± 0.55	10.20 ± 0.32	0.2627	0.1900	0.1147	3.3648	0.6	5.608

from the positron lifetime results, for the NMS samples is roughly 10% higher than that of ONMS, which is consistent with the observations of CDBS. Since O₂ doping is there in ONMS, the peak of CDBS is slightly shifted towards $P_L = 8.5 \times 10^{-3} m_0 c$, which indirectly hints at the annihilation of positrons with the 2p electrons of O₂ atoms ($P_L = 8.5 \times 10^{-3} m_0 c$).

The as-grown NMS and ONMS samples along with pristine MoS₂ (MS) were employed to study their antifungal properties on fungal pathogens, namely, *Alternaria alternata* and *Fusarium oxysporum* and to understand whether doping with elements of different electronegativities affects the fungal inhibition process. The fungitoxicity of the MoS₂ nanostructures, as found from our previous study, are highly dependent on their ROS (reactive oxygen species) generation capacity both in dark and under visible light irradiation.³⁷ The fungitoxicity of ONMS,

NMS, and MS were determined in terms of their fungal growth inhibition capacity, which was determined by calculating the radial growth reduction in 5 day-old fungal colonies as compared to the control experiment [Fig. S5–S7, ESI†]. The bare MoS₂(MS) sample, owing to its poor ROS generation capacity, failed to dominate over the fungal ROS scavenging machinery. Hence, no significant fungal inhibition was observed for the bare MS samples. However, doping nitrogen atoms into MoS₂ is seen to result in accelerated fungitoxic effects under dark, as revealed by the digital photographs of NMS-treated fungal colonies, which gets further enhanced when treated under visible light irradiation. In the presence of visible light, NMS nanosheets (0.5 mg mL⁻¹) shows 12.5% radial growth inhibition towards *A. alternata*, which is 2.12 times greater than that measured under dark experiments [Fig. 5(b)]. However, the

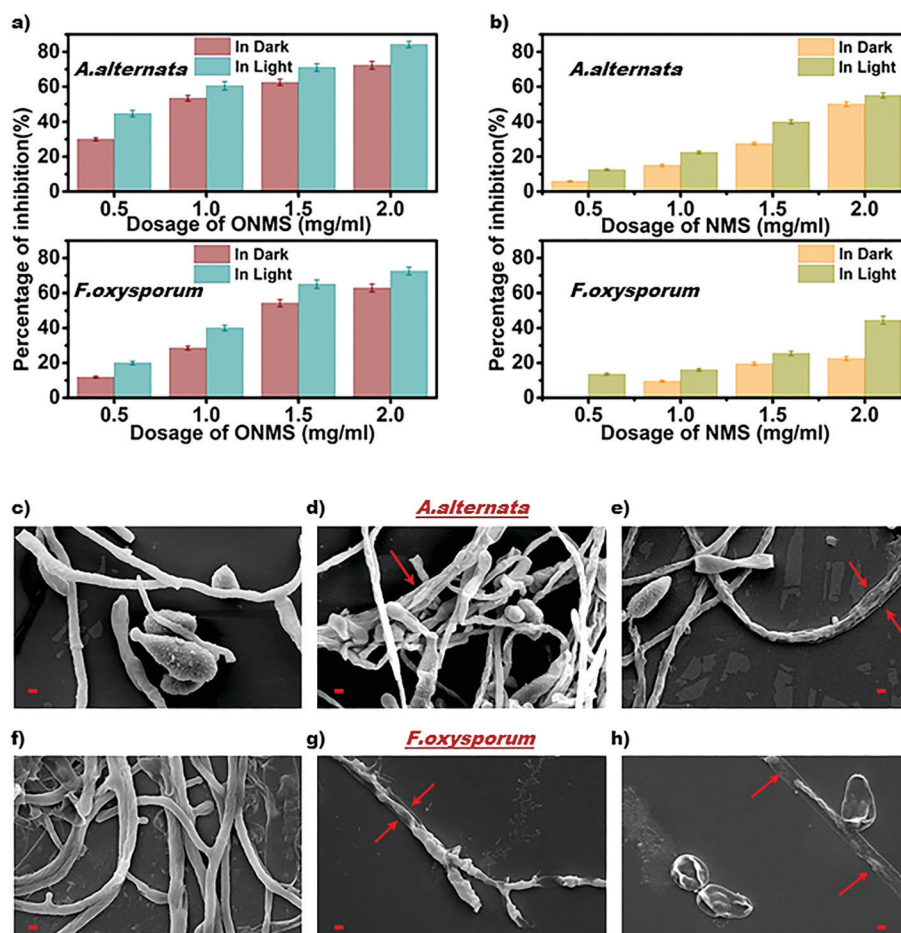


Fig. 5 Graphical representation of (a) ONMS and (b) NMS-induced radial growth inhibition in *A. alternata* and *F. oxysporum*. The data represented are statistically significant ($p < 0.05$); scanning electron micrographs of *A. alternata* and *F. oxysporum* (c and f) without treatment, (d and g) ONMS treatment with a dosage of 2 mg mL⁻¹ in dark, (e and h) ONMS treatment with a dosage of 2 mg mL⁻¹ under visible light. All scale bars in red color represent a length of 2 μm.



fungitoxicity of the NMS nanostructures increased in a dose dependent manner. Under visible light illumination and for a concentration of 2 mg mL^{-1} , NMS nanostructures showed nearly 55% mycelial growth retardation in *A. alternata*, which is 1.1 times higher than the growth retardation achieved with treatment under dark conditions. For *F. oxysporum*, at lower dosage (0.5 mg mL^{-1}), NMS showed a 12.5% growth inhibition upon light irradiation, which is very similar to that for *A. alternata*. However, when treated with 2 mg mL^{-1} concentration, the fungitoxicity doubles on visible light exposure [Fig. 5(b)]. Higher fungitoxicity in the presence of visible light illumination supports the photo-induced acceleration of ROS generation, resulting in greater cell death. Being a super oxidizing agent, the introduction of oxygen in the MoS_2 nanostructure, in addition to nitrogen, accelerated its fungitoxicity further, as expected in the case of ONMS.

Fig. 5(a) shows that for a 2 mg mL^{-1} concentration and upon visible light treatment, ONMS successfully suppressed 84.21% mycelial growth of *A. alternata*, which is 16.47% higher than the retardation obtained under dark experimental conditions. Likewise, under visible light, for *F. oxysporum*, ONMS nanoflowers achieved a fungal growth retardation of 72.54% with a dosage of 2 mg mL^{-1} , which was 15.41% higher when treated under dark. Comparing the results obtained for NMS and the ONMS nanoflowers, it is evident that the introduction of oxygen into MoS_2 increased their fungitoxicity ~ 1.5 and ~ 1.6 times for *A. alternata* and *F. oxysporum*, respectively [Fig. 5(a) and (b)].

The biochemical assessment of fungal cell viability after ONMS treatment were performed by TTC assay.⁶³ Both the

pathogens were treated with different doses of ONMS nanoflowers for 24 hours, followed by the addition of TTC reagent and further incubation for 12 hours. The dehydrogenase enzymes secreted by viable fungal cells reduced TTC into a red coloured compound, namely, formazan, which was dissolved in dimethyl sulfoxide (DMSO) and detected spectrophotometrically at 570 nm. Cell viability was correlated with formazan formation and is presented in Fig. S8 (ESI[†]). In a line similar to the radial growth inhibition assay, ONMS nanoflowers exhibited higher toxicity towards *A. alternata* than *F. oxysporum*, which are $\sim 86\%$ and 75% , respectively.

Further, the evaluation of the ONMS nanoflower-induced morphological deformities in the fungal cells with reference to the untreated biomass were carried out using an scanning electron microscope and is presented in [Fig. 5(c)–(h)]. For both the pathogens, the smooth surfaced untreated fungal mycelia with a distinct outline gets completely distorted on being treated with doped MoS_2 nanoflowers. The release of intra-cellular materials, as evident from the SEM images of the ONMS-treated fungal biomass, is a clear indication of ROS-induced perforations within the cell wall, resulting in its higher permeability, which thereby leads to compulsive cell death. Detection of real-time ROS generation by ONMS nanosheets was performed using DCF dye (dichlorofluorescein) and their effect upon the fungal biomass has been captured under a fluorescence microscope and is presented in Fig. 6. In the case of untreated fungal mycelia, no fluorescence was detected, which indicated the absence of ROS in normal fungal mycelia. In contrast, when treated with ONMS nanoparticles,

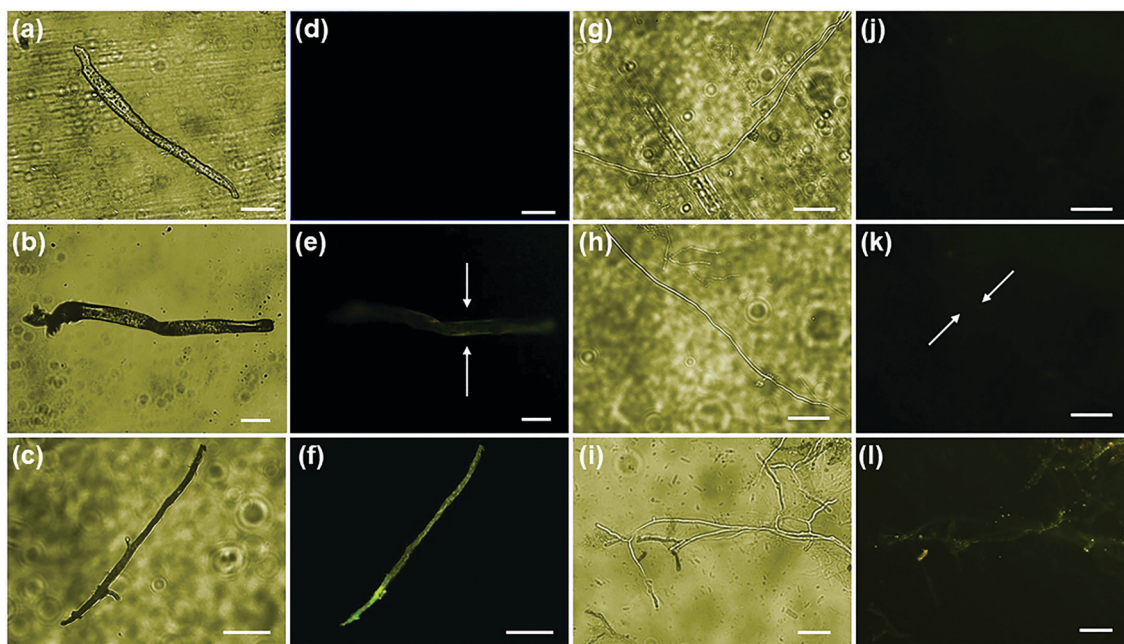


Fig. 6 Fluorescence microscopic imaging of Reactive Oxygen Species (ROS) in ONMS (2 mg mL^{-1}) labelled fungal mycelia. Bright field image of (a–c) *A. alternata* and (g–i) *F. oxysporum* under various conditions. (a and g) Without treatment; (b and h) ONMS treated and grown under dark; (c and i) ONMS treated and grown under visible light irradiation. Fluorescent images of (d–f) *A. alternata* and (j–l) *F. oxysporum* under different conditions. (d and j) without treatment; (e and k) ONMS treated and grown under dark; (f and l) ONMS treated and grown under visible light irradiation. All scale bars in white represent a length of $50 \mu\text{m}$.



the emission of green fluorescence was detected upon blue excitation, indicating nanoparticle-induced ROS generation onto the mycelial surface, causing plausible cellular damage and deformities. Again, nanomaterial treatment under visible light illumination shows higher emission of green fluorescence, which supports photo-induced elevation in ROS generation by the nanosheets [Fig. 6].

Nanoparticle-induced fungal cell death has also been confirmed by fluorescence microscopy using EtBr staining (ethidium bromide). The perforated cell wall of the nanoparticle-treated fungal biomass allows EtBr binding with DNA material, showing red fluorescence upon green excitation [Fig. 7]. The prominent emission of red fluorescence evident in ONMS and NMS-treated fungal mycelia under visible light irradiation can be attributed as a confirmation of photo-induced accelerated ROS generation [Fig. 6]. However, no red fluorescence was seen in the case of untreated fungal mycelia, which signifies the characteristic rigidity and integrity of the chitin layer, thus successfully eliminating EtBr entry at the intracellular matrix. ROS generation propensity of MoS₂ and engineered N-doped MoS₂ had been well-documented.^{30,37} The superoxide $\cdot\text{O}_2^-$ and hydroxyl $\cdot\text{OH}$ radicals generated under dark and visible light illumination possess strong oxidation potential. The production of excessive ROS at the cellular environment dominates over its ROS scavenging machinery, thus altering the redox balance at the intracellular level. The impairment in cellular redox-balance imposes the oxidative stress on the cell membrane and affects the membrane permeability severely, leading to compulsive cell death. The generation of superoxide molecules triggers a series of redox reactions inside the cell, synthesizing more toxic molecules that cause

oxidation of DNA, lipid, proteins, enzymes, oxidation of water into hydroxyl radical ($\cdot\text{OH}$), and production of toxic H₂O₂ molecule. The de-activation of glutathione (GSH) and GSH-related enzymes is one of the most studied toxicological implications of superoxide molecules. GSH plays an important role in the cellular anti-oxidant system.⁶⁴ The oxidation of the -SH group of GSH enzymes leads to stable disulphide (-S-S-) bond formation, resulting in functional inactivation of the enzyme. Consequently, the susceptibility of the fungal cells to the toxic oxidants multiplies several times, exposing it to higher risk of cellular damages. Other than that, the superoxide molecule potentially oxidizes important biomolecules such as DNA, RNA, protein, and lipids, and triggers cellular apoptosis and aging.^{37,65}

Oxidation of water molecules generates $\cdot\text{OH}$ radicals that exhibit significant oxidation potential. It strongly reacts with the H atom of the *N*-acetyl-glucosamine monomer of the chitin layer and breaks the 1,4 and 1,6-glycosidic linkages, disturbing the characteristic rigidity and integrity of the fungal cell wall. In addition, $\cdot\text{OH}$ radicals also oxidizes intracellular bio-molecules of the microbial cell, thus altering the cellular biochemistry.^{63,66} A schematic representation of the ROS-mediated antifungal mechanism is given in Fig. 8. Superoxide molecules are reduced to H₂O₂ and their toxicity to the cell is multi-dimensional. It is actively involved in enhancing cellular apoptosis by DNA fragmentation and chromatin condensation. Higher accumulation of H₂O₂ at the cellular level also results in lipid peroxidation and protein oxidation, thus impairing the cellular stability.⁶⁷

The antifungal effect of ONMS was by far better than that of NMS, both in light and in dark. As there is not much significant difference in terms of morphology, vacancy states, and porosity,

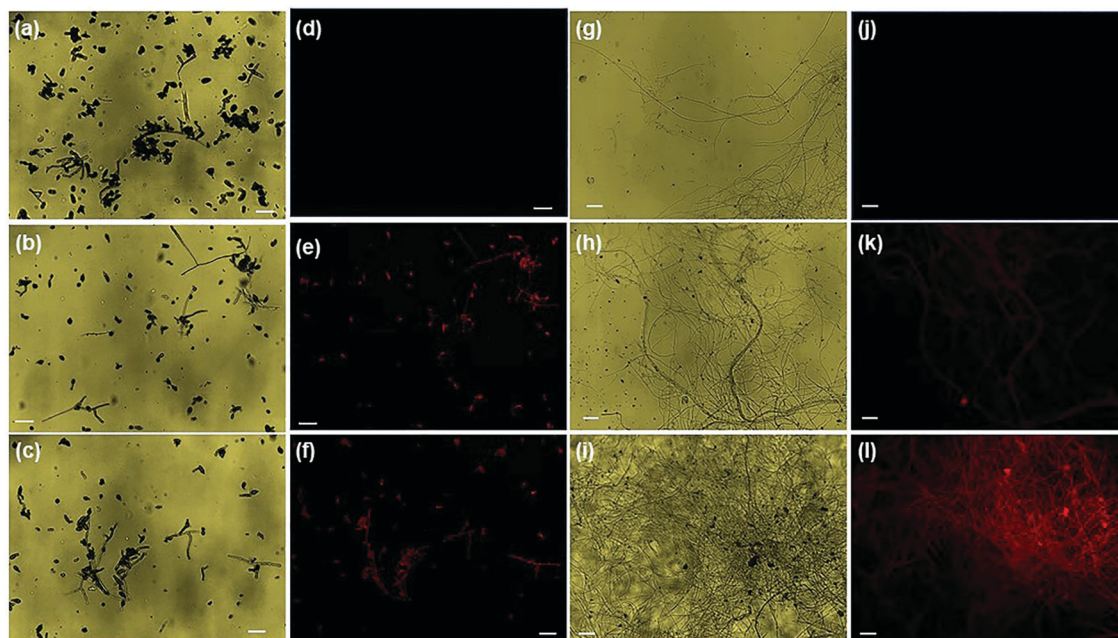


Fig. 7 Fluorescence imaging of fungal DNA by EtBr intercalation through ONMS (2 mg mL⁻¹) treated perforated cell wall. Bright field images of *A. alternata* and *F. oxysporum* (a and g) without treatment; (b and h) treated with ONMS under dark; (c and i) treated with ONMS under visible light irradiation. Fluorescence imaging of *A. alternata* and *F. oxysporum* (d and j) without treatment; (e and k) treated with ONMS under dark; (f and l) treated with ONMS under visible light irradiation. All scale bars in white are 50 μm in length.



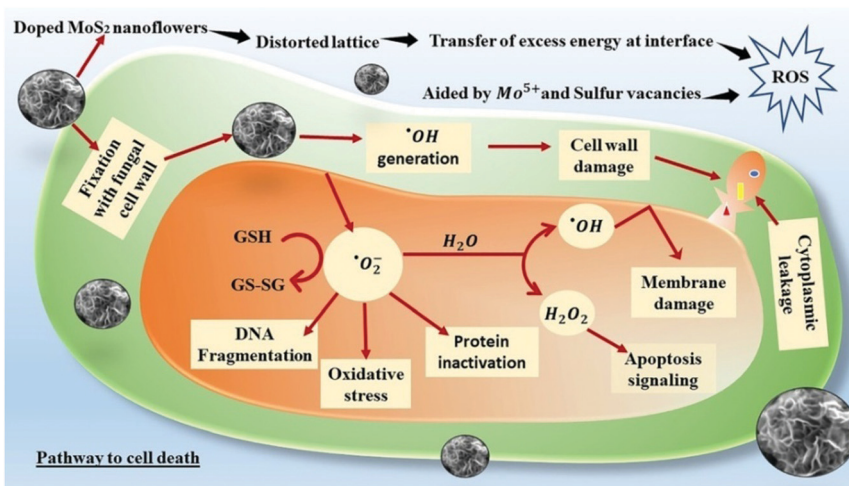


Fig. 8 Schematic representation of the ROS-mediated pathway leading to compulsive cell death.

the better antifungal performance of ONMS in comparison to NMS may be attributed to the elevated levels of ROS generation from the Mo^{5+} sites in ONMS. Interestingly, unlike our previous work,³⁷ in which the S-vacancies played a pivotal role in the spontaneous generation of ROS by N-doped MoS_2 , ROS generation in the dark in the present study for ONMS was prompted upon by the different mechanism. Because of distortion due to oxygen and nitrogen co-doping, the ONMS lattice is under strain, as revealed from the Raman spectroscopy analysis. On being brought in contact with the aqueous environment (cellular water and constituent water part in the fungal growth media), the strain in doped MoS_2 is relaxed and there is a spontaneous transfer of elastic energy stored in the lattice, which thereby triggers the generation of ROS in dark. ROS generation is further augmented under visible light illumination as a result of electron-hole pair generation, which react with dissolved oxygen to form the ROS species. MoS_2 being a semiconductor, on being excited with energies greater than its band gap energy, the electrons on its valence band are excited to move to the conduction band, thus creating holes in the VB.³⁰ The better antifungal performance of ONMS originates from the presence of Mo^{5+} sites in ONMS, as revealed from the EPR studies, which are the active hubs of ROS generation in this case.

The uniqueness and superiority of ONMS over most other nanomaterial-based fungicides lie in the fact that it can generate ROS in dark, which gets enhanced on being illuminated with visible light. Apart from its use in usual antifungal applications, this paves the way for its application in antifungal coatings in implantable medical devices. A comparative study of ONMS with other 2D-nanolayer-based antifungals is given in Table S1 of the ESI,[†] which shows that the effectiveness towards fungal inhibition of the present sample is in good competition with the presently available fungicides. Further, in order to address the issue of biocompatibility, it may be mentioned here that the constituent elements (Mo and S) of the nanomaterial used in this study are established micro-nutrients that promote

plant growth and metabolism. Moreover, bare MoS_2 , as a compound, does not exhibit any toxicity, which is experimentally evident from our study [Fig. S7, ESI[†]]. The toxicity in other samples is purely ROS mediated and achieved by introducing N and O into the nanostructure. Further, the EC_{50} (concentration of $\sim 50\%$ growth inhibition) value of ONMS for *A. alternata* and *F. oxysporum* are 1.0 and 1.5 mg mL^{-1} , respectively. Although, the minute concentration of the nanomaterial is high enough to control the fungal pathogens, the plant's antioxidant system can easily scavenge the ROS generated by the applied nanomaterials. Moreover, there are numerous reports of the excellent biocompatibility of MoS_2 and N-doped MoS_2 .^{68,69} However, to figure out the influence of ONMS on the plant body and to address the issue of biocompatibility, a small experiment was conducted with potato tubers, which ensured the biocompatibility of the present materials towards plant cell. The details of the experiment have been given in the ESI[†] (Section S1.3).

4. Conclusions

In summary, we have successfully incorporated oxygen and nitrogen atoms in MoS_2 nanoflowers through an optimised and facile hydrothermal method and studied the antifungal effects of the synthesized samples on fungal pathogens, namely, *A. alternata* and *F. oxysporum*. The HRTEM, XRD, Raman, XPS, and EPR characterisation results confirmed the presence of O-doping in ONMS. The PAS studies revealed that the overall defect constitution in ONMS and NMS is almost similar with very little differences in the defect history of the two samples. Moreover, doping with oxygen and nitrogen atoms resulted in excellent antifungal activities in MoS_2 , which otherwise showed no antifungal growth inhibition whatsoever. The antifungal performance of ONMS was superior to that of NMS, both in dark and under visible light illumination. The superiority of ONMS over NMS was achieved through the careful design of the MoS_2 nanoflowers through oxygen doping to cultivate the Mo^{5+}



states within the lattice. These Mo⁵⁺ defect states in ONMS acted as the primary sites for ROS generation, thereby leading to an enhanced performance towards the inhibition of *A. alternata* and *F. oxysporum*. The present study will thus open up the avenue for the design of newer antifungals with lesser chances of antimicrobial resistance through suitable elemental doping in order to cope with the growing threats to global biodiversity due to unprecedented global warming.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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